

4.5 A, 600 V very fast IGBT with Ultrafast diode

Datasheet - production data

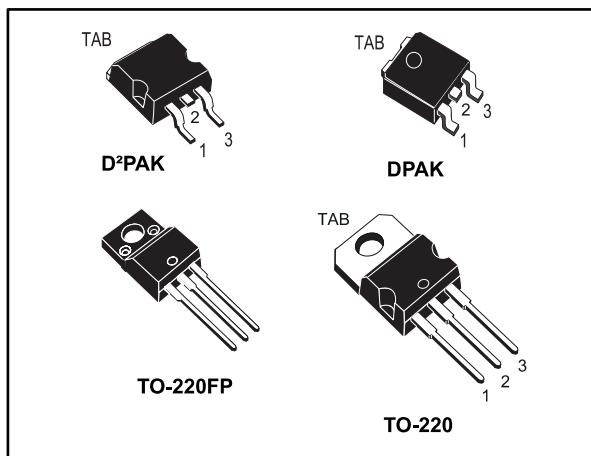


Figure 1: Internal schematic diagram

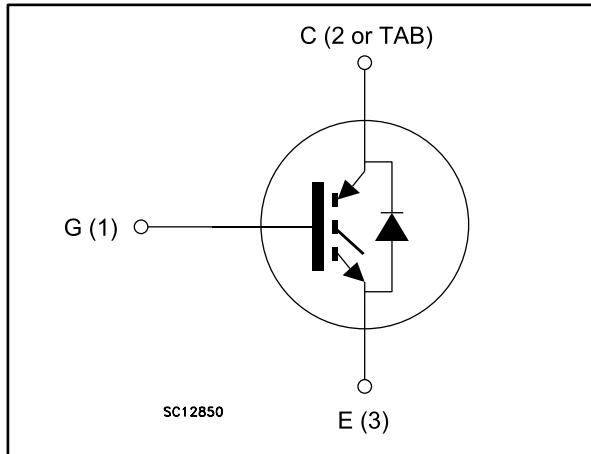


Table 1: Device summary

| Order code | Marking | Package | Packing |
|---------------|-----------|--------------------|---------------|
| STGB3HF60HD | GB3HF60HD | D ² PAK | Tape and reel |
| STGD3HF60HDT4 | GD3HF60HD | DPAK | Tape and reel |
| STGF3HF60HD | GF3HF60HD | TO-220FP | Tube |
| STGP3HF60HD | GP3HF60HD | TO-220 | Tube |

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1 Electrical ratings

Table 2: Absolute maximum ratings

| Symbol | Parameter | Value | | | Unit |
|--------------------------------|---|-------------|------------------------------|----------|------|
| | | DPAK | D ² PAK TO-220 | TO-220FP | |
| V _{CES} | Collector-emitter voltage ($V_{GE} = 0$) | 600 | | | V |
| I _c ⁽¹⁾ | Continuous collector current at $T_c = 25$ °C | 7.5 | | | A |
| I _c ⁽¹⁾ | Continuous collector current at $T_c = 100$ °C | 4.5 | | | A |
| I _{CL} ⁽²⁾ | Turn-off latching current | 18 | | | A |
| I _{CP} ⁽³⁾ | Pulsed collector current | 18 | | | A |
| V _{GE} | Gate-emitter voltage | ± 20 | | | V |
| I _F | Diode RMS forward current at $T_c = 25$ °C | 10 | | | A |
| I _{FSM} | Surge non repetitive forward current $t_p = 10$ ms sinusoidal | 25 | | | A |
| P _{TOT} | Total dissipation at $T_c = 25$ °C | 38 | 18 | | W |
| T _{STG} | Storage temperature range | - 55 to 150 | | | °C |
| T _j | Operating junction temperature range | | | | |

Notes:

⁽¹⁾Calculated according to the iterative formula:

$$I_C(T_c) = \frac{T_{j(max)} - T_c}{R_{thj-c} \times V_{CE(sat)(max)}(T_{j(max)}, I_C(T_c))}$$

⁽²⁾ $V_{clamp} = 80\%$, (V_{CES}), $T_j = 150$ °C, $R_G = 10$ Ω, $V_{GE} = 15$ V.

⁽³⁾Pulse width limited by maximum junction temperature range.

Table 3: Thermal data

| Symbol | Parameter | Value | | | Unit |
|-----------------------|--|-------|------------------------------|----------|------|
| | | DPAK | D ² PAK TO-220 | TO-220FP | |
| R _{thj-case} | Thermal resistance junction-case IGBT | 3.3 | | 6.9 | °C/W |
| | Thermal resistance junction-case diode | 5 | | 8 | °C/W |
| R _{thj-amb} | Thermal resistance junction-ambient | 100 | 62.5 | | °C/W |

2 Electrical characteristics

($T_j=25^\circ\text{C}$ unless otherwise specified).

Table 4: Static electrical characteristics

| Symbol | Parameter | Test conditions | Min. | Typ. | Max. | Unit |
|-----------------------------|--|---|------|------|-----------|---------------|
| $V_{(\text{BR})\text{CES}}$ | Collector-emitter breakdown voltage ($V_{GE} = 0$) | $I_C = 1 \text{ mA}$ | 600 | | | V |
| $V_{CE(\text{sat})}$ | Collector-emitter saturation voltage | $V_{GE} = 15 \text{ V}, I_C = 0.5 \text{ A}, T_j = 125^\circ\text{C}$ | | 1.4 | | V |
| | | $V_{GE} = 15 \text{ V}, I_C = 1.5 \text{ A}$ | | 2.45 | 2.95 | |
| | | $V_{GE} = 15 \text{ V}, I_C = 1.5 \text{ A}, T_j = 125^\circ\text{C}$ | | 1.85 | | |
| $V_{GE(\text{th})}$ | Gate threshold voltage | $V_{CE} = V_{GE}, I_C = 250 \mu\text{A}$ | 3.75 | | 5.75 | V |
| I_{CES} | Collector cut-off current ($V_{GE} = 0$) | $V_{CE} = 600 \text{ V}$ | | | 250 | μA |
| | | $V_{CE} = 600 \text{ V}, T_j = 125^\circ\text{C}$ | | | 1 | mA |
| I_{GES} | Gate-emitter leakage current ($V_{CE} = 0$) | $V_{GE} = \pm 20 \text{ V}$ | | | ± 100 | nA |
| g_{fs} | Forward transconductance | $V_{CE} = 15 \text{ V}, I_C = 1.5 \text{ A}$ | | 1.5 | | S |

Table 5: Dynamic electrical characteristics

| Symbol | Parameter | Test conditions | Min. | Typ. | Max. | Unit |
|-----------|------------------------------|--|------|------|------|------|
| C_{ies} | Input capacitance | $V_{CE} = 25 \text{ V}, f = 1 \text{ MHz}, V_{GE} = 0$ | - | 152 | - | pF |
| C_{oes} | Output capacitance | | - | 14 | - | pF |
| C_{res} | Reverse transfer capacitance | | - | 3 | - | pF |
| Q_g | Total gate charge | $V_{CE} = 480 \text{ V}, I_C = 1.5 \text{ A}, V_{GE} = 15 \text{ V}$ (see Figure 18: "Gate charge test circuit") | - | 12 | - | nC |
| Q_{ge} | Gate-emitter charge | | - | 2 | - | nC |
| Q_{gc} | Gate-collector charge | | - | 6 | - | nC |

Table 6: Switching on/off (inductive load)

| Symbol | Parameter | Test conditions | Min. | Typ. | Max. | Unit |
|----------------|-----------------------|--|------|------|------|------------------|
| $t_{d(on)}$ | Turn-on delay time | $V_{CC} = 400 \text{ V}, I_C = 1.5 \text{ A}$ $R_G = 100 \Omega, V_{GE} = 15 \text{ V}$ (see Figure 17: "Test circuit for inductive load switching" Figure 19: "Switching waveform") | - | 11 | - | ns |
| t_r | Current rise time | | - | 4 | - | ns |
| $(di/dt)on$ | Turn-on current slope | | - | 285 | - | A/ μs |
| $t_{d(on)}$ | Turn-on delay time | $V_{CC} = 400 \text{ V}, I_C = 1.5 \text{ A}$ $R_G = 100 \Omega, V_{GE} = 15 \text{ V}$ $T_j = 125^\circ\text{C}$ (see Figure 17: "Test circuit for inductive load switching" Figure 19: "Switching waveform") | - | 10 | - | ns |
| t_r | Current rise time | | - | 5 | - | ns |
| $(di/dt)on$ | Turn-on current slope | | - | 265 | - | A/ μs |
| $t_r(V_{off})$ | Off voltage rise time | $V_{CC} = 400 \text{ V}, I_C = 1.5 \text{ A}$, $R_{GE} = 100 \Omega, V_{GE} = 15 \text{ V}$ (see Figure 17: "Test circuit for inductive load switching" Figure 19: "Switching waveform") | - | 26 | - | ns |
| $t_{d(off)}$ | Turn-off delay time | | - | 60 | - | ns |
| t_f | Current fall time | | - | 50 | - | ns |
| $t_r(V_{off})$ | Off voltage rise time | $V_{CC} = 400 \text{ V}, I_C = 1.5 \text{ A}$, $R_{GE} = 100 \Omega, V_{GE} = 15 \text{ V}$, $T_j = 125^\circ\text{C}$ (see Figure 17: "Test circuit for inductive load switching" Figure 19: "Switching waveform") | - | 64 | - | ns |
| $t_{d(off)}$ | Turn-off delay time | | - | 69 | - | ns |
| t_f | Current fall time | | - | 71 | - | ns |

Table 7: Switching energy (inductive load)

| Symbol | Parameter | Test conditions | Min. | Typ. | Max. | Unit |
|-----------------------------|---------------------------|---|------|------|------|---------------|
| $E_{on}^{(1)}$ | Turn-on switching energy | $V_{CC} = 400 \text{ V}, I_C = 1.5 \text{ A}$ $R_G = 100 \Omega, V_{GE} = 15 \text{ V}$ (see Figure 17: "Test circuit for inductive load switching" Figure 19: "Switching waveform") | - | 19 | - | μJ |
| $E_{off}^{(2)}$ E_{ts} | Turn-off switching energy | | - | 12 | - | μJ |
| E_{ts} | Total switching energy | | - | 31 | - | μJ |
| $E_{on}^{(1)}$ | Turn-on switching energy | $V_{CC} = 400 \text{ V}, I_C = 1.5 \text{ A}$ $R_G = 100 \Omega, V_{GE} = 15 \text{ V}$, $T_j = 125^\circ\text{C}$ (see Figure 17: "Test circuit for inductive load switching" Figure 19: "Switching waveform") | - | 38 | - | μJ |
| $E_{off}^{(2)}$ | Turn-off switching energy | | - | 35 | - | μJ |
| E_{ts} | Total switching energy | | - | 73 | - | μJ |

Notes:

⁽¹⁾Eon is the turn-on energy when a typical diode is used in the test circuit in [Figure 17: "Test circuit for inductive load switching"](#). If the IGBT is offered in a package with a co-pak diode, the co-pak diode is used as external diode. IGBTs and diode are at the same temperature (25 °C and 125 °C).

⁽²⁾Turn-off energy include also the tail of the collector current.

Electrical characteristics

STGB3HF60HD, STGD3HF60HDT4,
STGF3HF60HD, STGP3HF60HD

Table 8: Collector-emitter diode

| Symbol | Parameter | Test conditions | Min. | Typ. | Max. | Unit |
|-----------|--------------------------|---|------|------|------|------|
| V_F | Forward on-voltage | $I_F = 1.5 \text{ A}$ | - | 1.4 | 1.8 | V |
| | | $I_F = 1.5 \text{ A}, T_j = 125 \text{ }^\circ\text{C}$ | - | 1.15 | | |
| t_{rr} | Reverse recovery time | | - | 85 | | ns |
| Q_{rr} | Reverse recovery charge | $I_F = 1.5 \text{ A}, V_R = 40 \text{ V},$ $di/dt = 100 \text{ A}/\mu\text{s}$ (see Figure 20: "Diode reverse recovery waveform") | - | 124 | | nC |
| | | | - | 3 | | A |
| t_{rr} | Reverse recovery time | | - | 114 | | ns |
| Q_{rr} | Reverse recovery charge | $I_F = 1.5 \text{ A}, V_R = 40 \text{ V},$ $T_j = 125 \text{ }^\circ\text{C}, di/dt = 100 \text{ A}/\mu\text{s}$ (see Figure 20: "Diode reverse recovery waveform") | - | 194 | | nC |
| | | | - | 3.5 | | A |
| I_{rrm} | Reverse recovery current | | | | | |

2.1 Electrical characteristics (curves)

Figure 2: Output characteristics

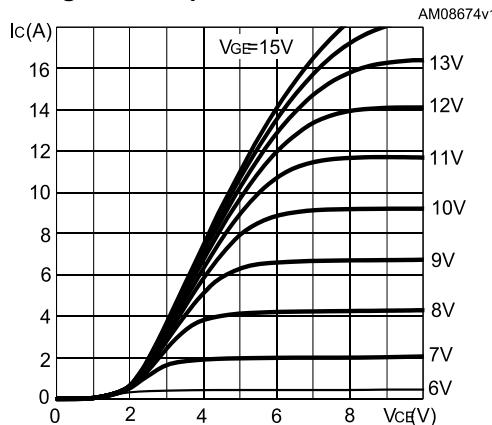


Figure 3: Output characteristic details

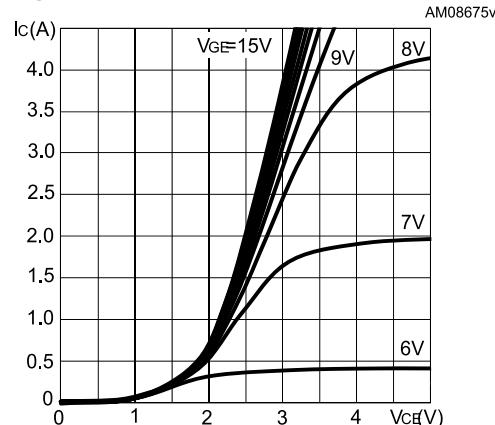


Figure 4: Transfer characteristics

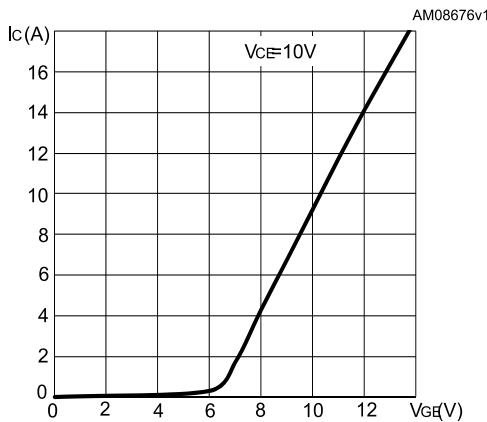


Figure 5: Collector-emitter on voltage vs collector current

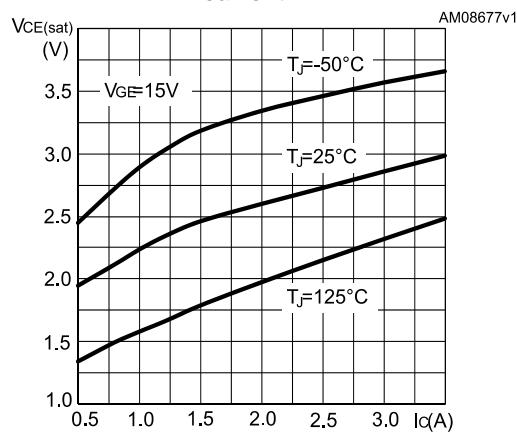


Figure 6: Collector-emitter on voltage vs temperature

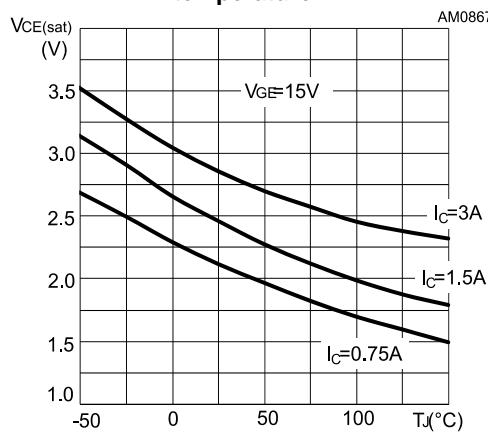
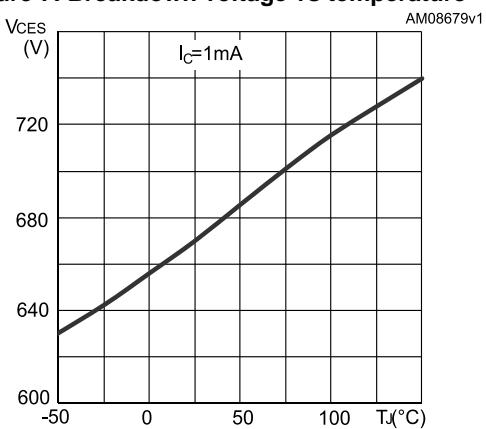


Figure 7: Breakdown voltage vs temperature



Electrical characteristics

**STGB3HF60HD, STGD3HF60HDT4,
STGF3HF60HD, STGP3HF60HD**

Figure 8: Gate threshold voltage vs temperature

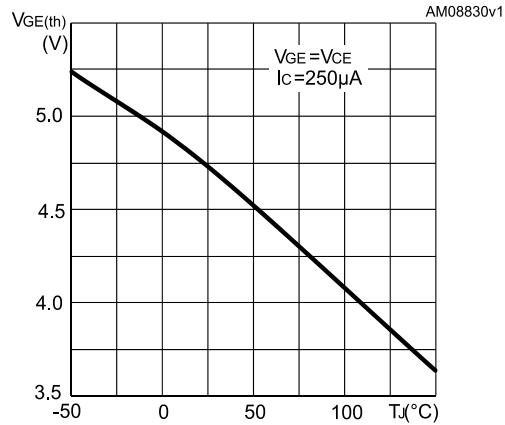


Figure 9: Gate charge vs gate-emitter voltage

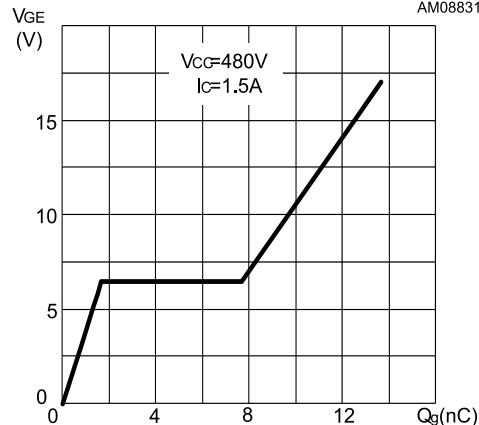


Figure 10: Capacitance variations

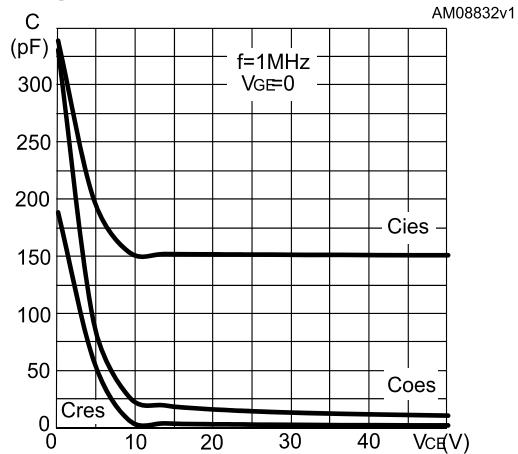


Figure 11: Switching energy vs collector current

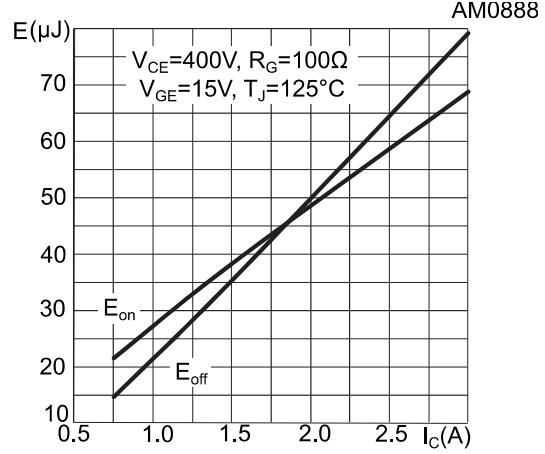


Figure 12: Switching energy vs gate resistance

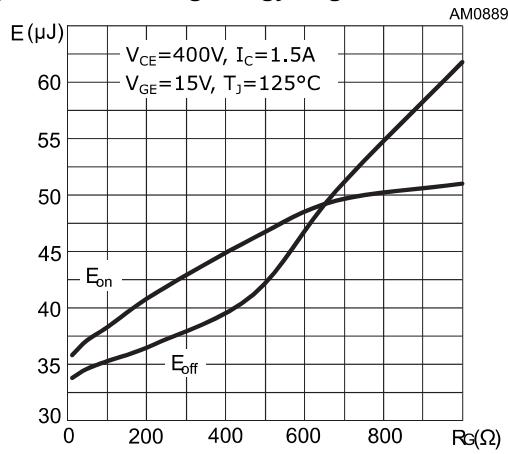


Figure 13: Switching energy vs temperature

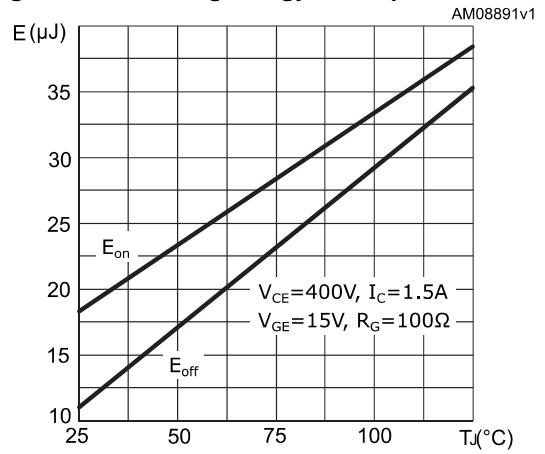
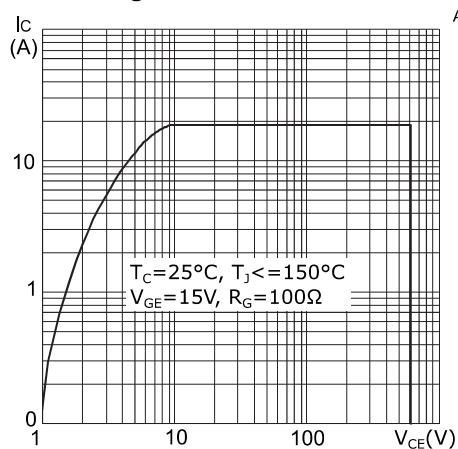
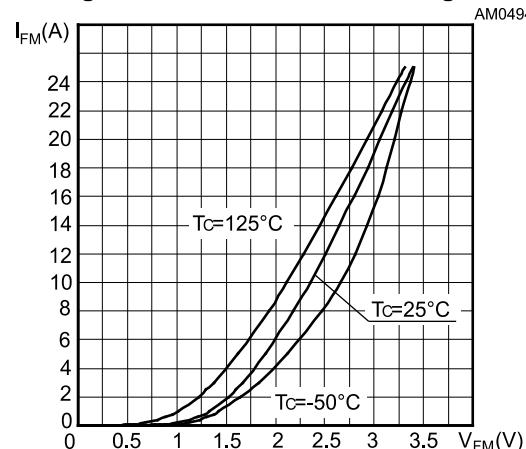


Figure 14: Turn-off SOA



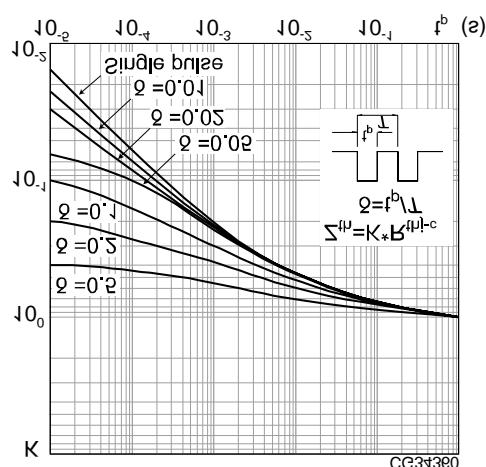
AM08836v1

Figure 15: Diode forward on voltage



AM04940v1

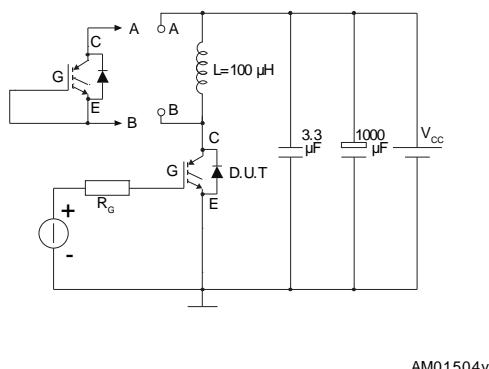
Figure 16: Thermal impedance



CC34360

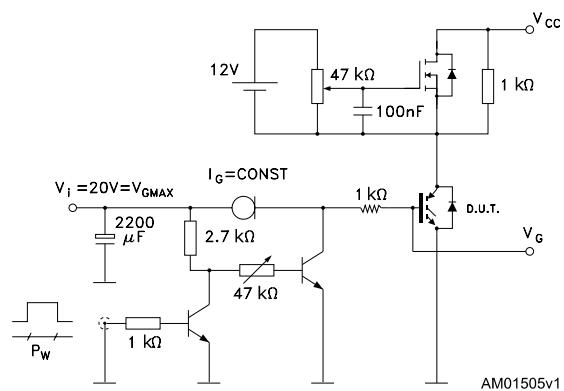
3 Test circuits

Figure 17: Test circuit for inductive load switching



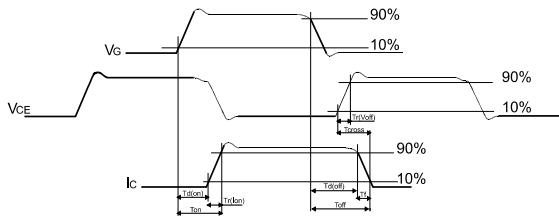
AM01504v1

Figure 18: Gate charge test circuit



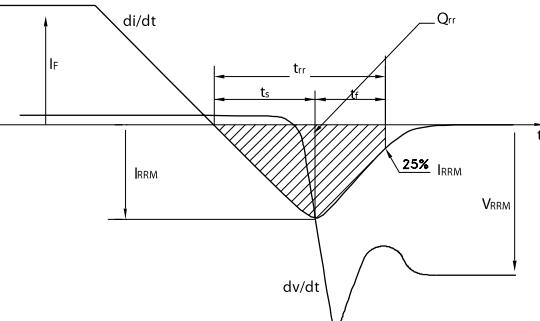
AM01505v1

Figure 19: Switching waveform



AM01506v1

Figure 20: Diode reverse recovery waveform



AM01507v1

4 Package information

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK® packages, depending on their level of environmental compliance. ECOPACK® specifications, grade definitions and product status are available at: www.st.com.
ECOPACK® is an ST trademark.

4.1 D²PAK (TO-263) package information

Figure 21: D²PAK (TO-263) type A package outline

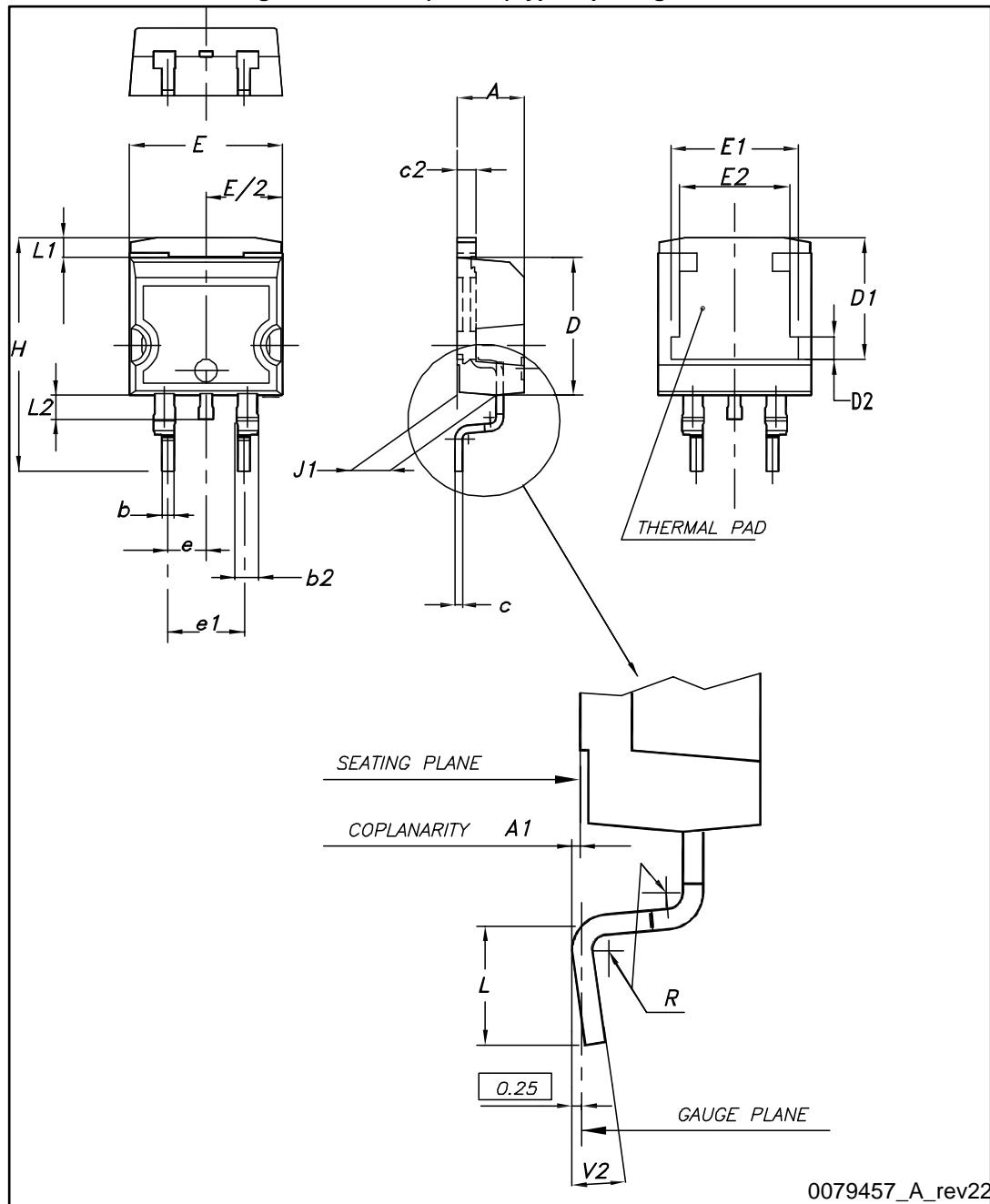
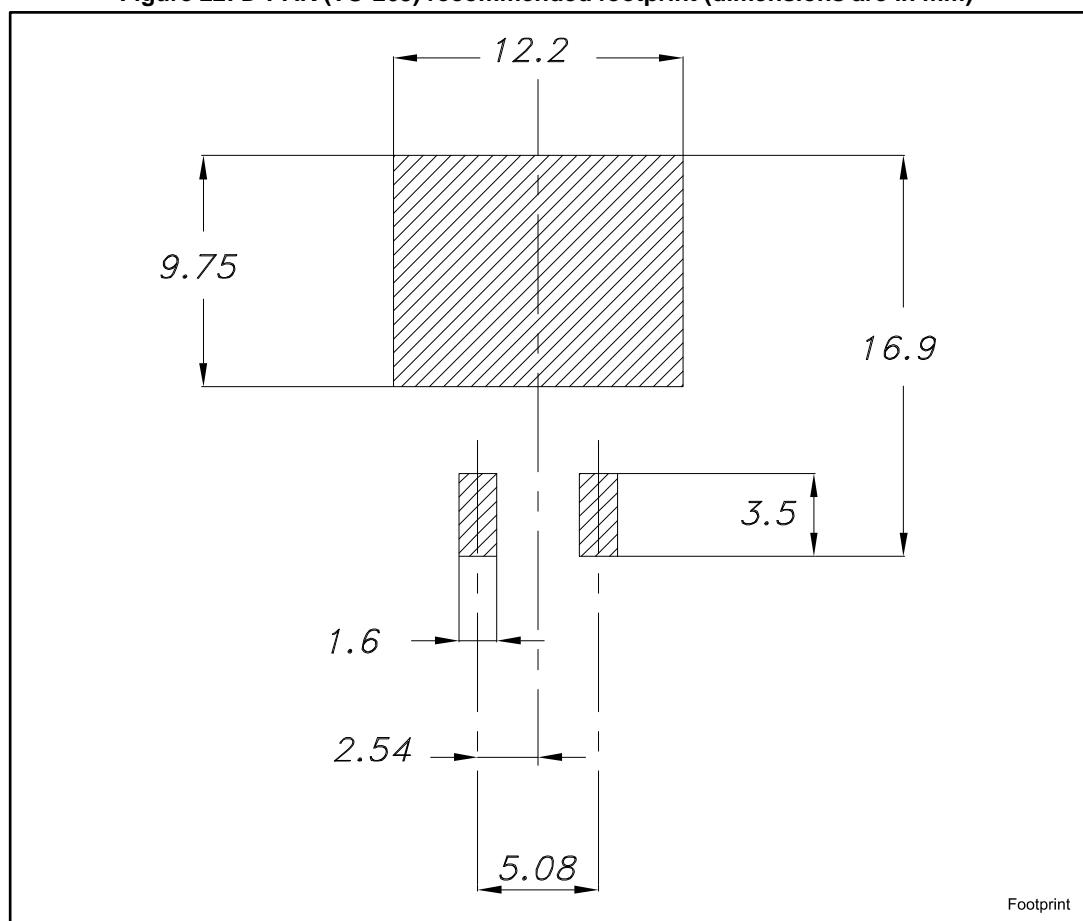


Table 9: D²PAK (TO-263) type A package mechanical data

| Dim. | mm | | |
|------|------|------|-------|
| | Min. | Typ. | Max. |
| A | 4.40 | | 4.60 |
| A1 | 0.03 | | 0.23 |
| b | 0.70 | | 0.93 |
| b2 | 1.14 | | 1.70 |
| c | 0.45 | | 0.60 |
| c2 | 1.23 | | 1.36 |
| D | 8.95 | | 9.35 |
| D1 | 7.50 | 7.75 | 8.00 |
| D2 | 1.10 | 1.30 | 1.50 |
| E | 10 | | 10.40 |
| E1 | 8.50 | 8.70 | 8.90 |
| E2 | 6.85 | 7.05 | 7.25 |
| e | | 2.54 | |
| e1 | 4.88 | | 5.28 |
| H | 15 | | 15.85 |
| J1 | 2.49 | | 2.69 |
| L | 2.29 | | 2.79 |
| L1 | 1.27 | | 1.40 |
| L2 | 1.30 | | 1.75 |
| R | | 0.4 | |
| V2 | 0° | | 8° |

Figure 22: D²PAK (TO-263) recommended footprint (dimensions are in mm)



4.2 D²PAK (TO-263) packing information

Figure 23: Tape outline

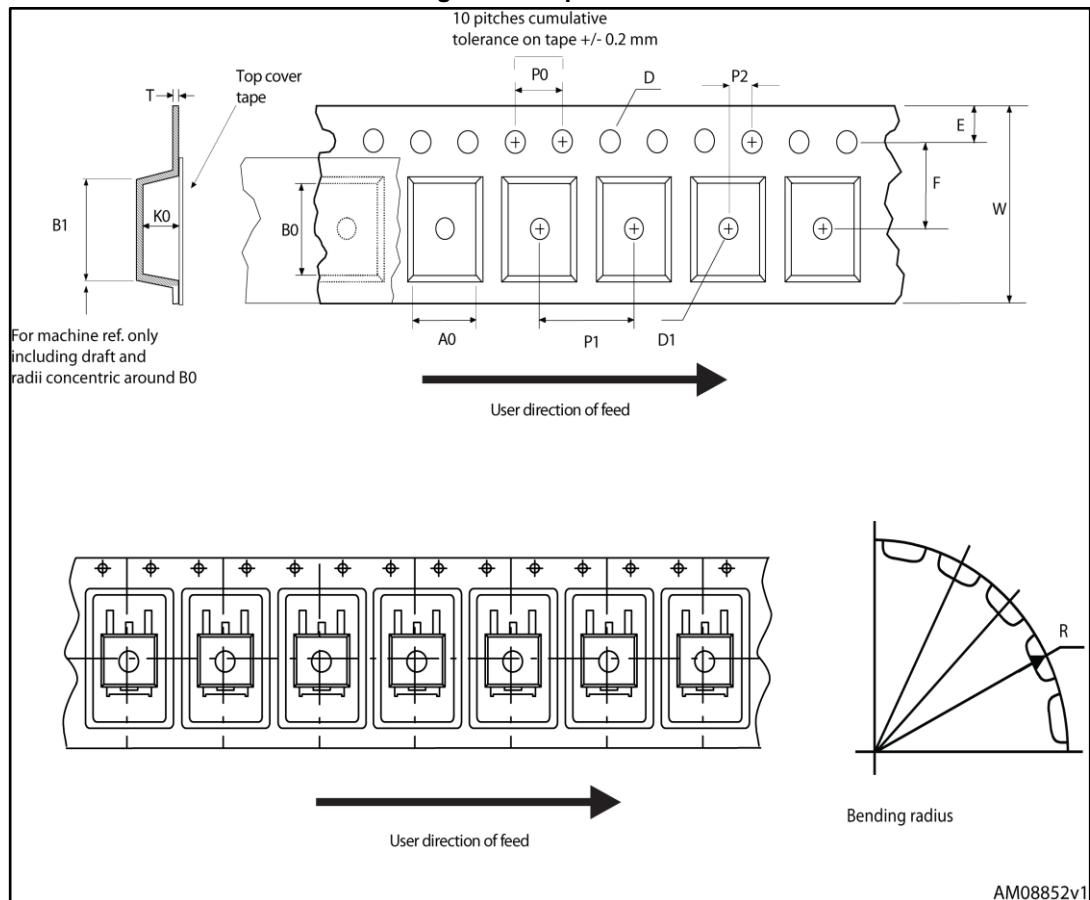


Figure 24: Reel outline

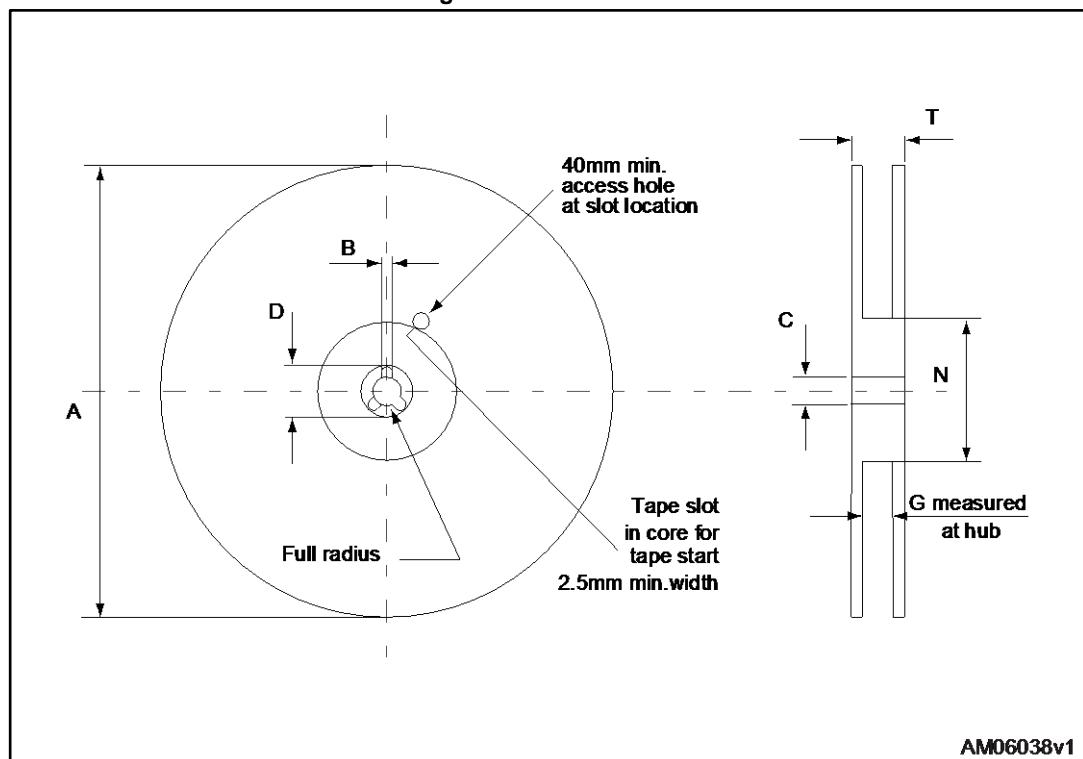
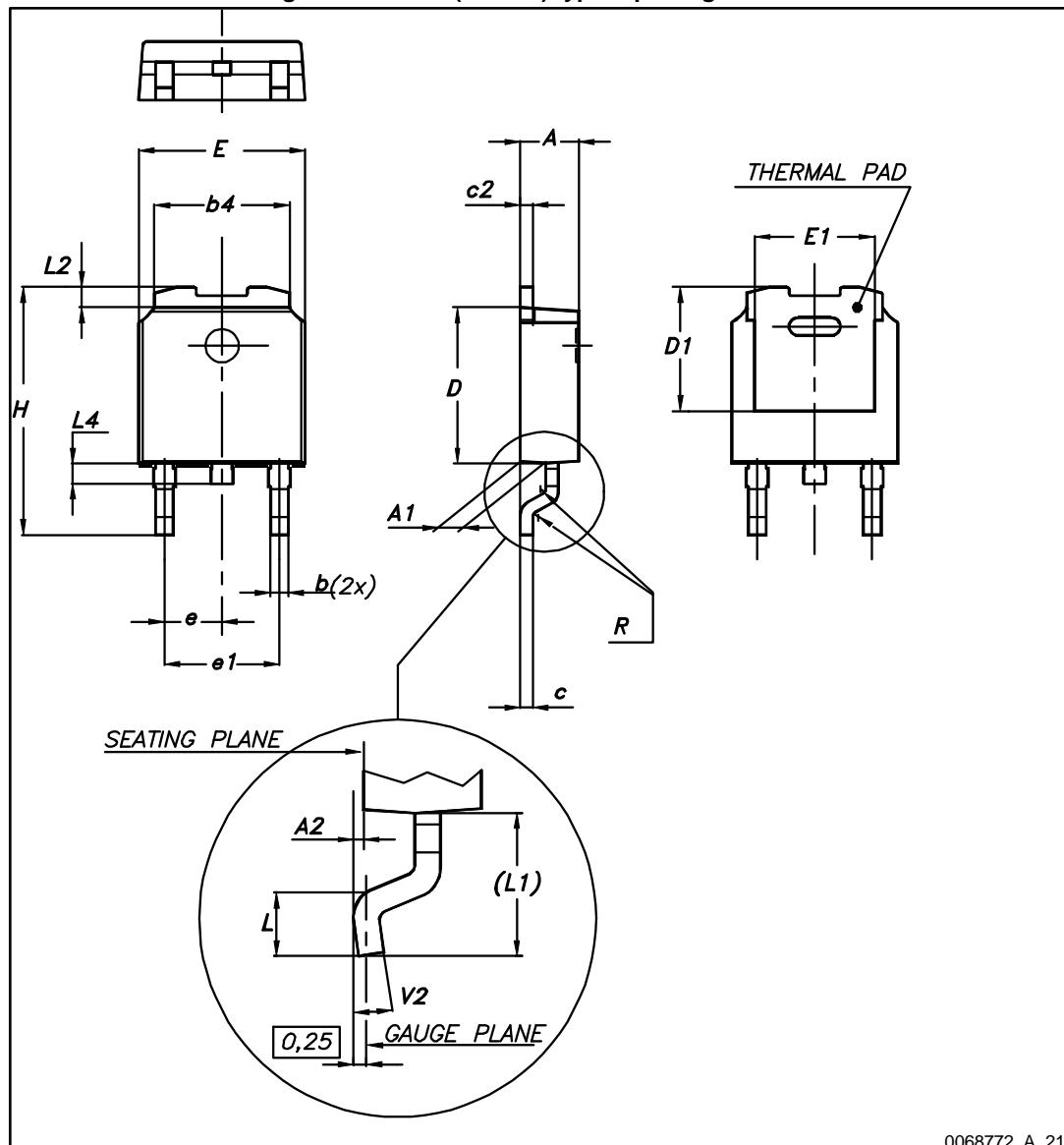


Table 10: D²PAK tape and reel mechanical data

| Tape | | | Reel | | |
|------|------|------|---------------|------|------|
| Dim. | mm | | Dim. | mm | |
| | Min. | Max. | | Min. | Max. |
| A0 | 10.5 | 10.7 | A | | 330 |
| B0 | 15.7 | 15.9 | B | 1.5 | |
| D | 1.5 | 1.6 | C | 12.8 | 13.2 |
| D1 | 1.59 | 1.61 | D | 20.2 | |
| E | 1.65 | 1.85 | G | 24.4 | 26.4 |
| F | 11.4 | 11.6 | N | 100 | |
| K0 | 4.8 | 5.0 | T | | 30.4 |
| P0 | 3.9 | 4.1 | | | |
| P1 | 11.9 | 12.1 | Base quantity | | 1000 |
| P2 | 1.9 | 2.1 | Bulk quantity | | 1000 |
| R | 50 | | | | |
| T | 0.25 | 0.35 | | | |
| W | 23.7 | 24.3 | | | |

4.3 DPAK (TO-252) type A package information

Figure 25: DPAK (TO-252) type A package outline

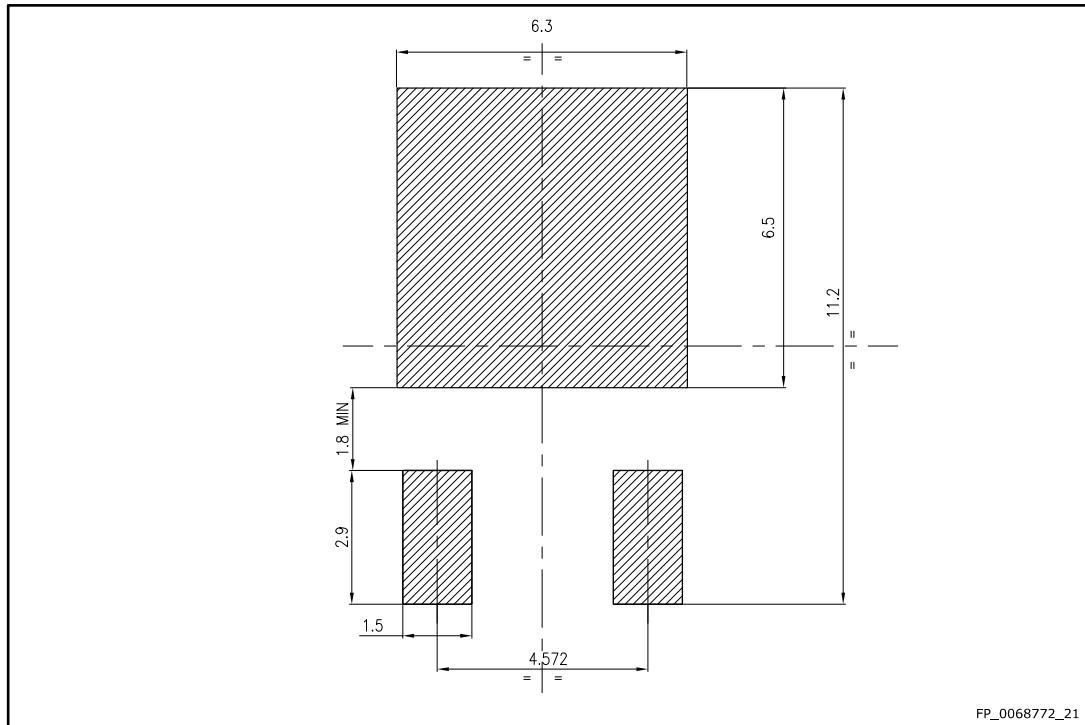


0068772_A_21

Table 11: DPAK (TO-252) type A mechanical data

| Dim. | mm | | |
|------|------|------|-------|
| | Min. | Typ. | Max. |
| A | 2.20 | | 2.40 |
| A1 | 0.90 | | 1.10 |
| A2 | 0.03 | | 0.23 |
| b | 0.64 | | 0.90 |
| b4 | 5.20 | | 5.40 |
| c | 0.45 | | 0.60 |
| c2 | 0.48 | | 0.60 |
| D | 6.00 | | 6.20 |
| D1 | 4.95 | 5.10 | 5.25 |
| E | 6.40 | | 6.60 |
| E1 | 4.60 | 4.70 | 4.80 |
| e | 2.16 | 2.28 | 2.40 |
| e1 | 4.40 | | 4.60 |
| H | 9.35 | | 10.10 |
| L | 1.00 | | 1.50 |
| (L1) | 2.60 | 2.80 | 3.00 |
| L2 | 0.65 | 0.80 | 0.95 |
| L4 | 0.60 | | 1.00 |
| R | | 0.20 | |
| V2 | 0° | | 8° |

Figure 26: DPAK (TO-252) recommended footprint (dimensions are in mm)



4.4 DPAK (TO-252) packing information

Figure 27: DPAK (TO-252) tape outline

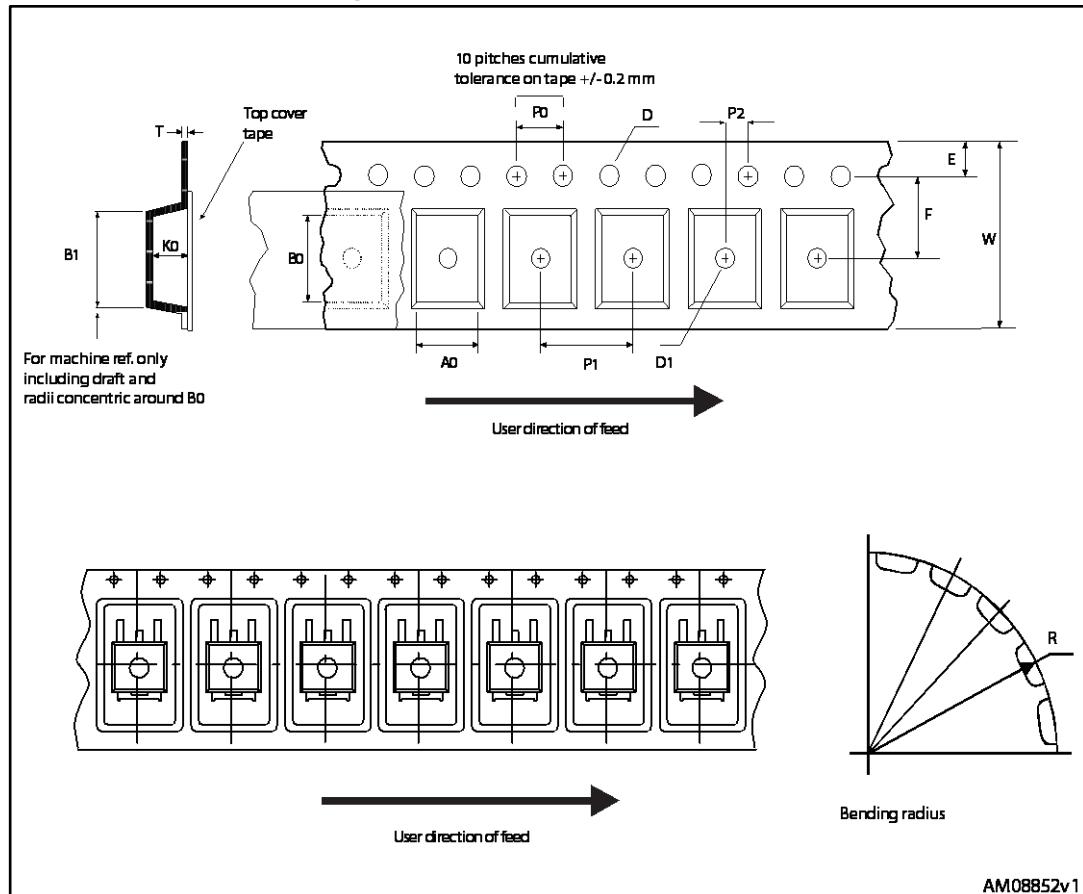


Figure 28: DPAK (TO-252) reel outline

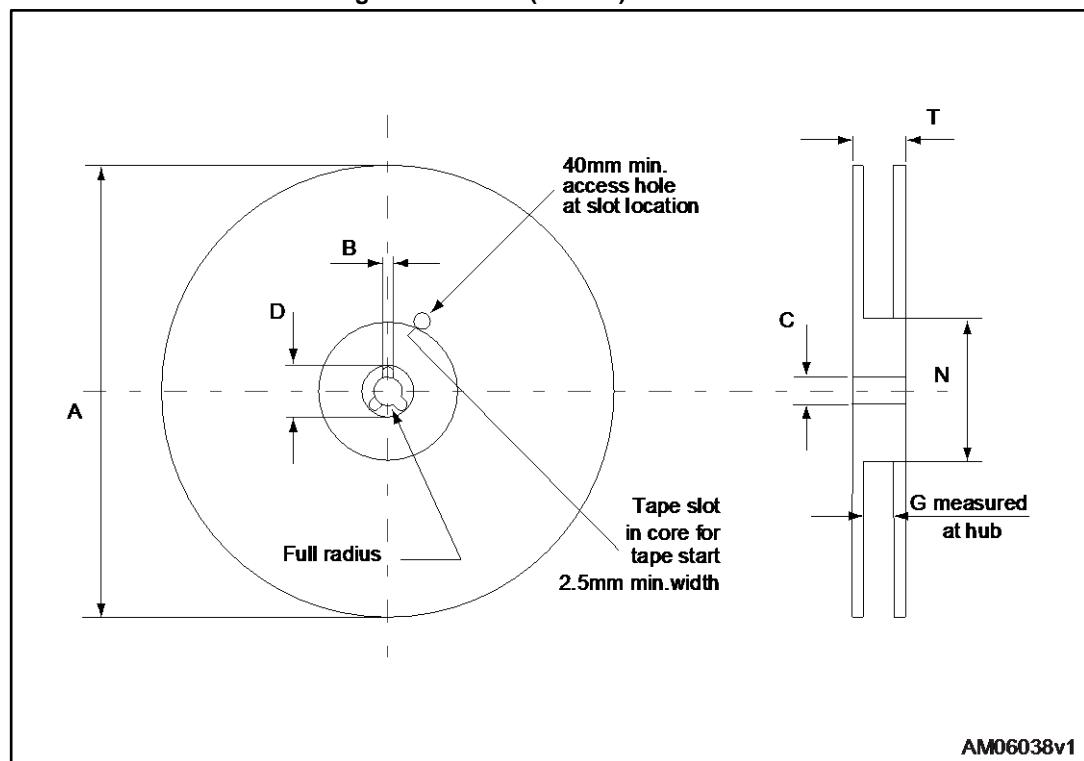


Table 12: DPAK (TO-252) tape and reel mechanical data

| Tape | | | Reel | | |
|------|------|------|-----------|------|------|
| Dim. | mm | | Dim. | mm | |
| | Min. | Max. | | Min. | Max. |
| A0 | 6.8 | 7 | A | | 330 |
| B0 | 10.4 | 10.6 | B | 1.5 | |
| B1 | | 12.1 | C | 12.8 | 13.2 |
| D | 1.5 | 1.6 | D | 20.2 | |
| D1 | 1.5 | | G | 16.4 | 18.4 |
| E | 1.65 | 1.85 | N | 50 | |
| F | 7.4 | 7.6 | T | | 22.4 |
| K0 | 2.55 | 2.75 | | | |
| P0 | 3.9 | 4.1 | Base qty. | | 2500 |
| P1 | 7.9 | 8.1 | Bulk qty. | | 2500 |
| P2 | 1.9 | 2.1 | | | |
| R | 40 | | | | |
| T | 0.25 | 0.35 | | | |
| W | 15.7 | 16.3 | | | |

4.5 TO-220FP package information

Figure 29: TO-220FP package outline

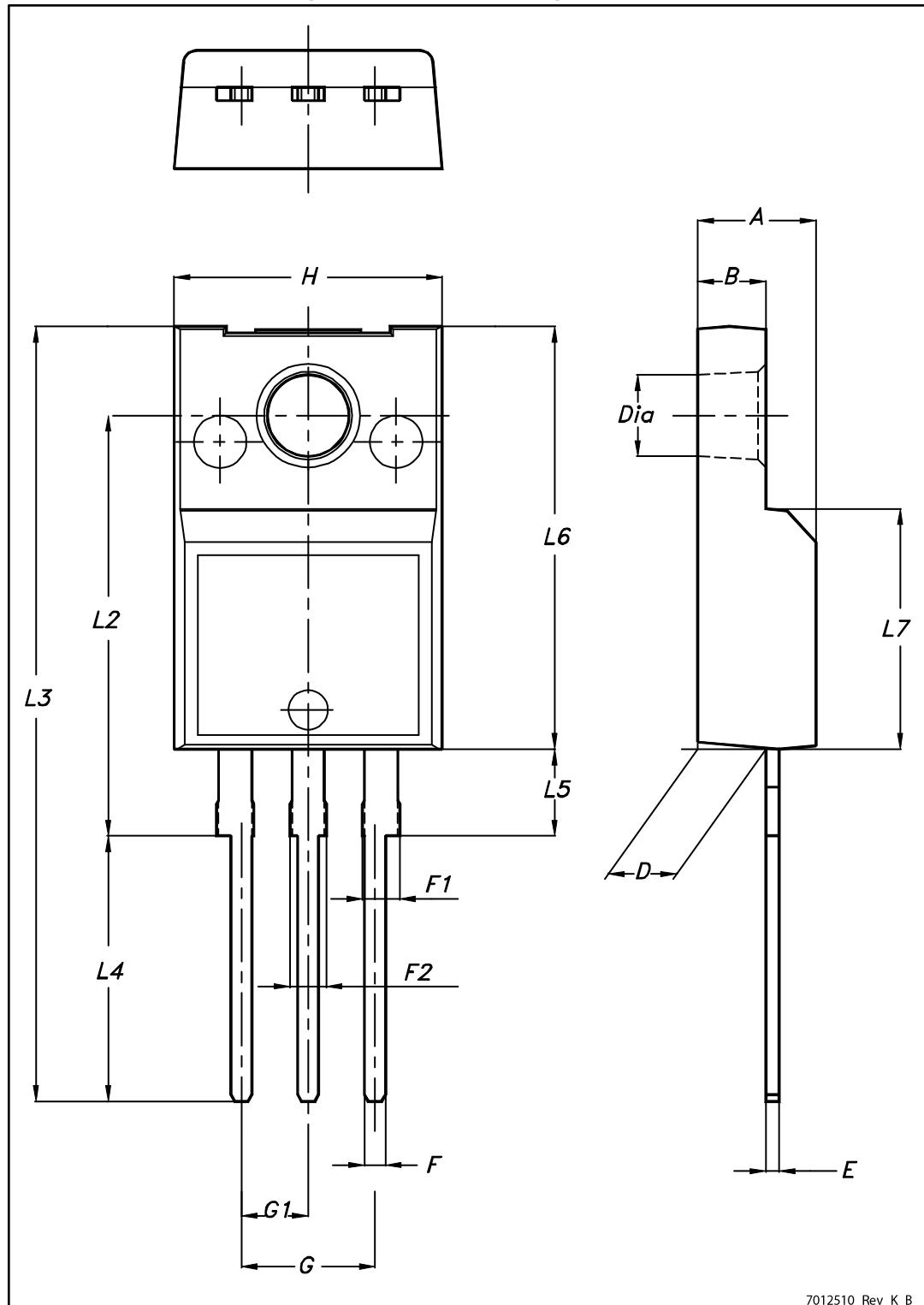


Table 13: TO-220FP package mechanical data

| Dim. | mm | | |
|------|------|------|------|
| | Min. | Typ. | Max. |
| A | 4.4 | | 4.6 |
| B | 2.5 | | 2.7 |
| D | 2.5 | | 2.75 |
| E | 0.45 | | 0.7 |
| F | 0.75 | | 1 |
| F1 | 1.15 | | 1.70 |
| F2 | 1.15 | | 1.70 |
| G | 4.95 | | 5.2 |
| G1 | 2.4 | | 2.7 |
| H | 10 | | 10.4 |
| L2 | | 16 | |
| L3 | 28.6 | | 30.6 |
| L4 | 9.8 | | 10.6 |
| L5 | 2.9 | | 3.6 |
| L6 | 15.9 | | 16.4 |
| L7 | 9 | | 9.3 |
| Dia | 3 | | 3.2 |

4.6 TO-220 type A package information

Figure 30: TO-220 type A package outline

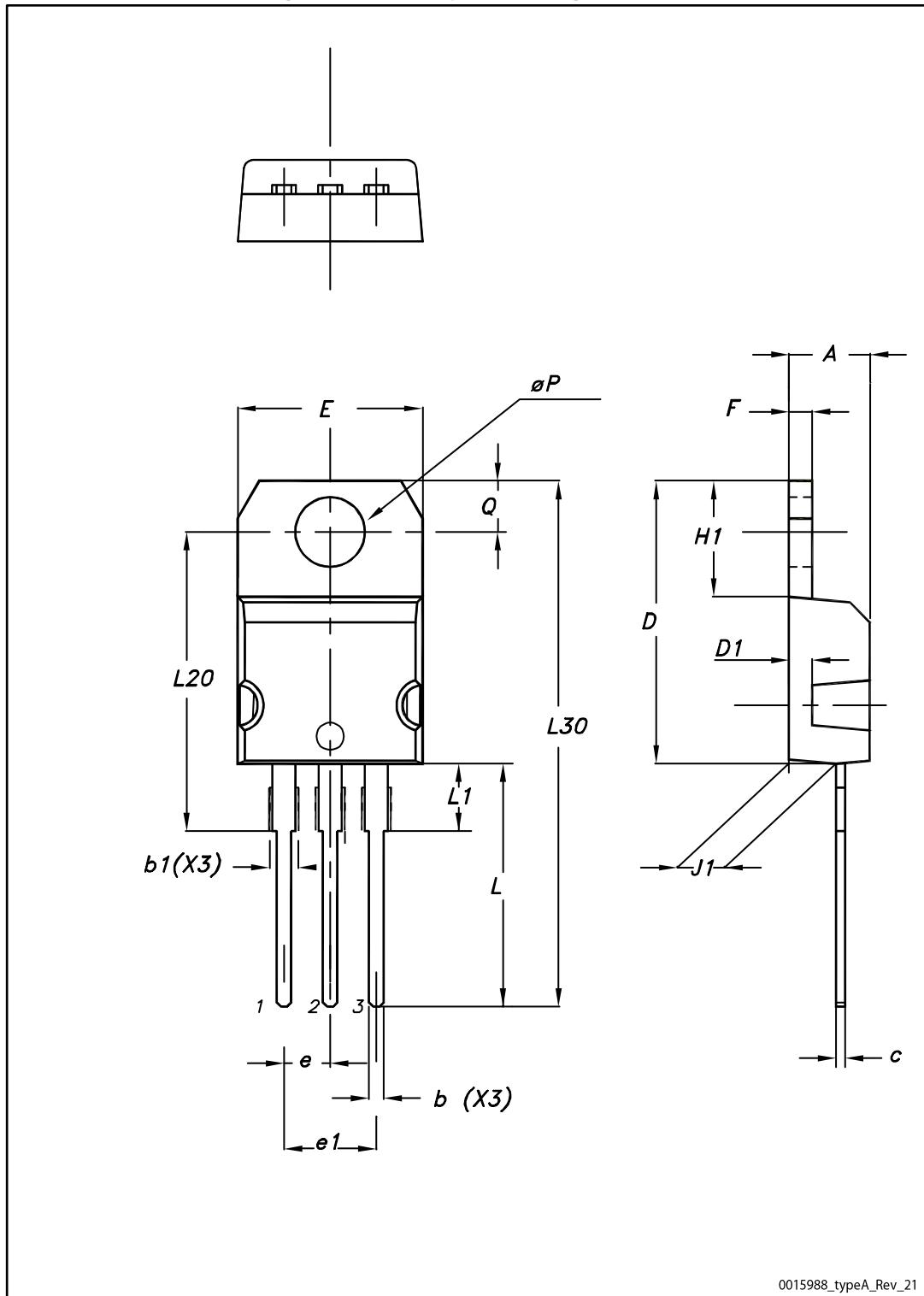


Table 14: TO-220 type A mechanical data

| Dim. | mm | | |
|------|-------|-------|-------|
| | Min. | Typ. | Max. |
| A | 4.40 | | 4.60 |
| b | 0.61 | | 0.88 |
| b1 | 1.14 | | 1.55 |
| c | 0.48 | | 0.70 |
| D | 15.25 | | 15.75 |
| D1 | | 1.27 | |
| E | 10.00 | | 10.40 |
| e | 2.40 | | 2.70 |
| e1 | 4.95 | | 5.15 |
| F | 1.23 | | 1.32 |
| H1 | 6.20 | | 6.60 |
| J1 | 2.40 | | 2.72 |
| L | 13.00 | | 14.00 |
| L1 | 3.50 | | 3.93 |
| L20 | | 16.40 | |
| L30 | | 28.90 | |
| øP | 3.75 | | 3.85 |
| Q | 2.65 | | 2.95 |

5 Revision history

Table 15: Document revision history

| Date | Revision | Changes |
|-------------|----------|--|
| 29-Jun-2010 | 1 | First release. |
| 09-Sep-2010 | 2 | Some values changed in <i>Table 2</i> . |
| 22-Dec-2010 | 3 | Document status promoted from preliminary data to datasheet. |
| 24-Sep-2013 | 4 | Added device in TO-220. Updated <i>Table 1: Device summary</i> , <i>Table 3: Thermal data</i> and <i>Section 4: Package mechanical data</i> accordingly. |
| 19-Sep-2016 | 5 | Added the order codes STGB3HF60HD and STGF3HF60HD. Added TO-220FP and D ² PAK packages. Updated <i>Table 1: "Device summary"</i> , <i>Section 1: "Electrical ratings"</i> , <i>Section 4: "Package information"</i> . Minor text changes. |

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